

COMLINEAR® CLC1002

Ultra-Low Noise Amplifier

FEATURES

- 0.6 nV/√Hz input voltage noise
- 1mV maximum input offset voltage
- 965MHz gain bandwidth product
- Minimum stable gain of 5
- 170V/μs slew rate
- 130mA output current
- -40°C to +125°C operating temperature range
- Fully specified at 5V and ±5V supplies
- CLC1002: Lead-free SOT23-6

APPLICATIONS

- Transimpedance amplifiers
- Pre-amplifier
- Low noise signal processing
- Medical instrumentation
- Probe equipment
- Test equipment
- Ultrasound channel amplifier

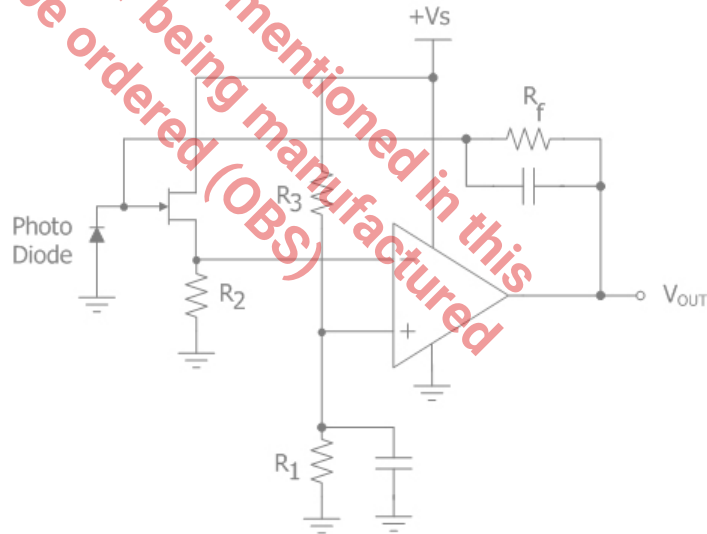
General Description

The COMLINEAR CLC1002(single) is a high-performance, voltage feed-back amplifier with ultra-low input voltage noise, 0.6nV/√Hz. The CLC1002 provides 965MHz gain bandwidth product and 170V/μs slew rate making it well suited for high-speed data acquisition systems requiring high levels of sensitivity and signal integrity. This COMLINEAR high-performance amplifier also offers low input offset voltage.

The COMLINEAR CLC1002 is designed to operate from 4V to 12V supplies. It consumes only 13mA of supply current per channel and offers a power saving disable pin that disables the amplifier and decreases the supply current to below 225μA. The CLC1002 amplifier operates over the extended temperature range of -40°C to +125°C.

If larger bandwidth or slew rate is required, a higher minimum stable gain version is available, the CLC1001 offers a minimum stable gain of 10 with 2.1GHz GBWP and 410V/μs slew rate.

Typical Application - Single Supply Photodiode Amplifier



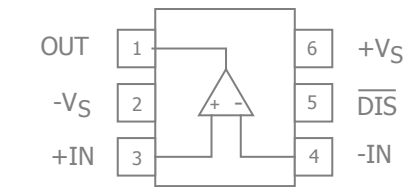
Ordering Information

Part Number	Package	Pb-Free	RoHS Compliant	Operating Temperature Range	Packaging Method
CLC1002IST6X	SOT23-6	Yes	Yes	-40°C to +125°C	Reel
CLC1002ISO8X	SOIC-8	Yes	Yes	-40°C to +125°C	Reel
CLC1002ISO8	SOIC-8	Yes	Yes	-40°C to +125°C	Rail

Moisture sensitivity level for all parts is MSL-1.



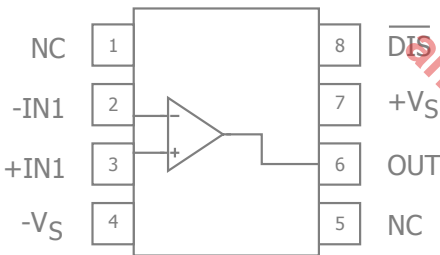
CLC1002 Pin Configuration



CLC1002 Pin Assignments

Pin No.	Pin Name	Description
1	OUT	Output
2	-VS	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	DIS	Disable. Enabled if pin is left floating or pulled above V_{ON} , disabled if pin is grounded or pulled below V_{OFF} .
6	+VS	Positive supply

SOIC Pin Configuration



SOIC Pin Assignments

Pin No.	Pin Name	Description
1	NC	No connect
2	-IN1	Negative input
3	+IN1	Positive input
4	-VS	Negative supply
5	NC	No connect
6	OUT	Output
7	+VS	Positive supply
8	DIS	Disable. Enabled if pin is left floating or pulled above V_{ON} , disabled if pin is grounded or pulled below V_{OFF} .



Absolute Maximum Ratings

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

Parameter	Min	Max	Unit
Supply Voltage	0	14	V
Input Voltage Range	$-V_S - 0.5V$	$+V_S + 0.5V$	V

Reliability Information

Parameter	Min	Typ	Max	Unit
Junction Temperature			150	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)			260	°C
Package Thermal Resistance				
6-Lead SOT23		177		°C/W
8-Lead SOIC		100		°C/W

Notes:

Package thermal resistance (θ_{JA}), JEDEC standard, multi-layer test boards, still air.

ESD Protection

Product	SOT23-6
Human Body Model (HBM)	2kV
Charged Device Model (CDM)	2kV

Recommended Operating Conditions

Parameter	Min	Typ	Max	Unit
Operating Temperature Range (CLC1002I)	-40		+85	°C
Operating Temperature Range (CLC1002A)	-40		+125	°C
Supply Voltage Range	4		12	V



Electrical Characteristics at +5V

$T_A = 25^\circ\text{C}$, $V_S = +5\text{V}$, $-V_S = \text{GND}$, $R_f = 100\Omega$, $R_L = 500\Omega$ to $V_S/2$, $G = 5$; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Frequency Domain Response						
GBWP	-3dB Gain Bandwidth Product	$G = +21$, $V_{OUT} = 0.2V_{pp}$		910		MHz
BW_{SS}	-3dB Bandwidth	$G = +5$, $V_{OUT} = 0.2V_{pp}$		265		MHz
BW_{LS}	Large Signal Bandwidth	$G = +5$, $V_{OUT} = 2V_{pp}$		54		MHz
$BW_{0.1dBSS}$	0.1dB Gain Flatness Small Signal	$G = +5$, $V_{OUT} = 0.2V_{pp}$		37		MHz
$BW_{0.1dBLS}$	0.1dB Gain Flatness Large Signal	$G = +5$, $V_{OUT} = 2V_{pp}$		29		MHz
Time Domain Response						
t_R , t_F	Rise and Fall Time	$V_{OUT} = 1\text{V}$ step; (10% to 90%)		4.2		ns
t_S	Settling Time to 0.1%	$V_{OUT} = 1\text{V}$ step		12		ns
OS	Overshoot	$V_{OUT} = 1\text{V}$ step		3		%
SR	Slew Rate	4V step		160		V/ μs
Distortion/Noise Response						
HD2	2nd Harmonic Distortion	$1V_{pp}$, 10MHz		-72		dBc
HD3	3rd Harmonic Distortion	$1V_{pp}$, 10MHz		-74		dBc
THD	Total Harmonic Distortion	$1V_{pp}$, 10MHz		-70		dB
e_n	Input Voltage Noise	> 100kHz		0.6		nV/ $\sqrt{\text{Hz}}$
i_n	Input Current Noise	> 100kHz		4.2		pA/ $\sqrt{\text{Hz}}$
DC Performance						
V_{IO}	Input Offset Voltage			0.1		mV
dV_{IO}	Average Drift			2.7		$\mu\text{V}/^\circ\text{C}$
I_b	Input Bias Current			28		μA
dI_b	Average Drift			46		nA/ $^\circ\text{C}$
I_o	Input Offset Current			0.1		μA
PSRR	Power Supply Rejection Ratio	DC		83		dB
A_{OL}	Open-Loop Gain	$V_{OUT} = V_S / 2$		80		dB
I_S	Supply Current	per channel		12.5		mA
Disable Characteristics						
t_{ON}	Turn On Time	1V step, 1% settling		80		ns
t_{OFF}	Turn Off Time			220		ns
OFF_{ISO}	Off Isolation	$2V_{pp}$, 5MHz		73		dB
$OFFC_{OUT}$	Off Output Capacitance			5.8		pF
V_{OFF}	Power Down Voltage	Disabled if $\overline{DIS}$ pin is grounded or pulled below V_{OFF}		Disabled if $\overline{DIS} < 1.5$		V
V_{ON}	Enable Voltage	Enabled if $\overline{DIS}$ pin is floating or pulled above V_{ON}		Enabled if $\overline{DIS} > 3$		V
I_{SD}	Disable Supply Current	No Load, $\overline{DIS}$ pin tied to ground		130		μA
Input Characteristics						
R_{IN}	Input Resistance	Non-inverting		4.2		M Ω
C_{IN}	Input Capacitance			2		pF
CMIR	Common Mode Input Range			0.8 to 5.1		V
CMRR	Common Mode Rejection Ratio	DC, $V_{cm} = 1.5\text{V}$ to 4V		94		dB
Output Characteristics						
V_{OUT}	Output Voltage Swing	$R_L = 500\Omega$		0.97 to 4		V
		$R_L = 2k\Omega$		0.96 to 4.1		V
I_{OUT}	Output Current			± 125		mA
I_{SC}	Short-Circuit Output Current	$V_{OUT} = V_S / 2$		± 150		mA

Notes:

- 100% tested at 25°C



Electrical Characteristics at $\pm 5V$

$T_A = 25^\circ\text{C}$, $V_S = \pm 5V$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Frequency Domain Response						
GBWP	-3dB Gain Bandwidth Product	$G = +21$, $V_{OUT} = 0.2V_{pp}$		965		MHz
BW_{SS}	-3dB Bandwidth	$G = +5$, $V_{OUT} = 0.2V_{pp}$		290		MHz
BW_{LS}	Large Signal Bandwidth	$G = +5$, $V_{OUT} = 2V_{pp}$		61		MHz
$BW_{0.1dBSS}$	0.1dB Gain Flatness Small Signal	$G = +5$, $V_{OUT} = 0.2V_{pp}$		45		MHz
$BW_{0.1dBLS}$	0.1dB Gain Flatness Large Signal	$G = +5$, $V_{OUT} = 2V_{pp}$		32		MHz
Time Domain Response						
t_R , t_F	Rise and Fall Time	$V_{OUT} = 1V$ step; (10% to 90%)		3.8		ns
t_S	Settling Time to 0.1%	$V_{OUT} = 1V$ step		12		ns
OS	Overshoot	$V_{OUT} = 1V$ step		2		%
SR	Slew Rate	2V step		170		V/ μ s
Distortion/Noise Response						
HD2	2nd Harmonic Distortion	$2V_{pp}$, 10MHz		-75		dBc
HD3	3rd Harmonic Distortion	$2V_{pp}$, 10MHz		-66		dBc
THD	Total Harmonic Distortion	$2V_{pp}$, 5MHz		-65.5		dB
e_n	Input Voltage Noise	> 100kHz		0.6		nV/ $\sqrt{\text{Hz}}$
i_n	Input Current Noise	> 100kHz		4.2		pA/ $\sqrt{\text{Hz}}$
DC Performance						
V_{IO}	Input Offset Voltage ⁽¹⁾		-1	0.5	1	mV
dV_{IO}	Average Drift			4.3		$\mu\text{V}/^\circ\text{C}$
I_b	Input Bias Current ⁽¹⁾		-60	30	60	μA
dI_b	Average Drift			44		nA/ $^\circ\text{C}$
I_o	Input Offset Current			0.3	6	μA
PSRR	Power Supply Rejection Ratio ⁽¹⁾	DC	78	83		dB
A_{OL}	Open-Loop Gain ⁽¹⁾	$V_{OUT} = V_S / 2$	70	83		dB
I_S	Supply Current ⁽¹⁾	per channel		13	16	mA
Disable Characteristics						
t_{ON}	Turn On Time	1V step, 1% settling		115		ns
t_{OFF}	Turn Off Time			210		ns
OFF_{ISO}	Off Isolation	$2V_{pp}$, 5MHz		73		dB
$OFFC_{OUT}$	Off Output Capacitance			5.7		pF
V_{OFF}	Power Down Voltage	Disabled if $\overline{DIS}$ pin is grounded or pulled below V_{OFF}		Disabled if $\overline{DIS} < 1.3$		V
V_{ON}	Enable Voltage	Enabled if $\overline{DIS}$ pin is floating or pulled above V_{ON}		Enabled if $\overline{DIS} > 3$		V
I_{SD}	Disable Supply Current ⁽¹⁾	No Load, $\overline{DIS}$ pin tied to ground		180	225	μA
Input Characteristics						
R_{IN}	Input Resistance	Non-inverting		9.4		M Ω
C_{IN}	Input Capacitance			1.82		pF
CMIR	Common Mode Input Range			-4.3 to 5		V
CMRR	Common Mode Rejection Ratio ⁽¹⁾	DC, $V_{cm} = -3.5V$ to $4V$	75	90		dB
Output Characteristics						
V_{OUT}	Output Voltage Swing	$R_L = 500\Omega$ ⁽¹⁾	-3.3	± 4	3.6	V
		$R_L = 2k\Omega$		± 4		V
I_{OUT}	Output Current			± 130		mA
I_{SC}	Short-Circuit Output Current	$V_{OUT} = V_S / 2$		± 165		mA

Notes:

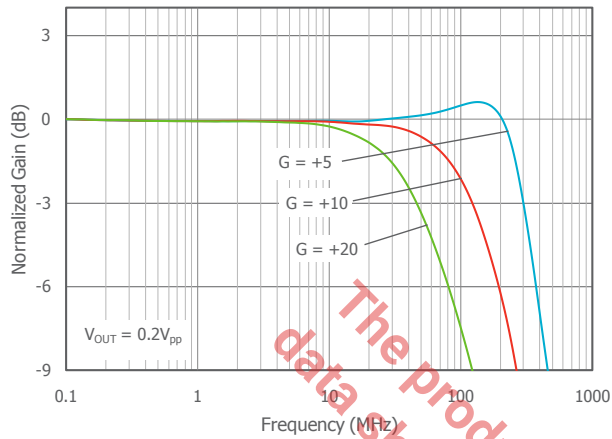
1. 100% tested at 25°C



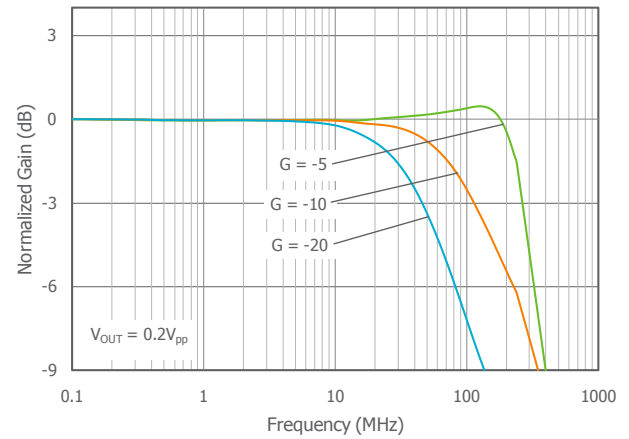
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

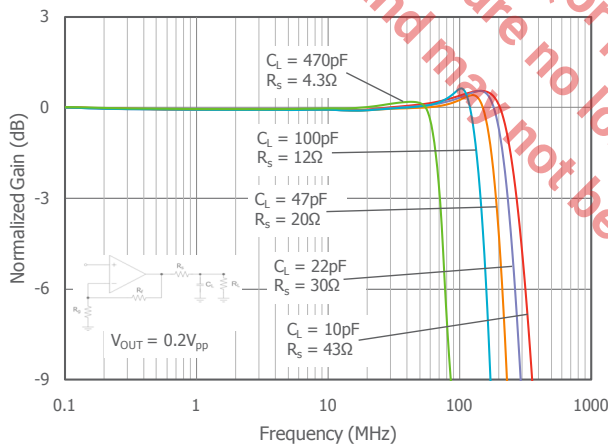
Non-Inverting Frequency Response



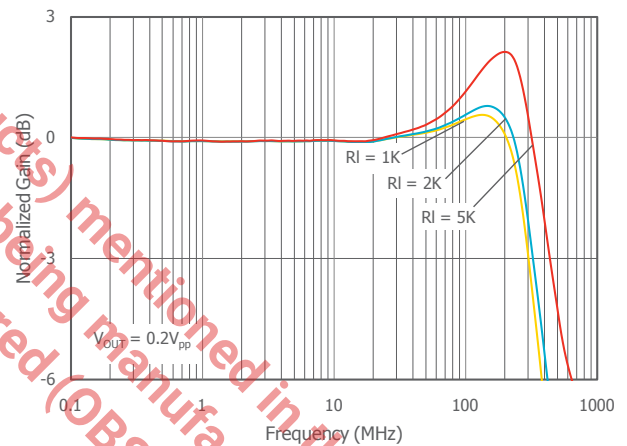
Inverting Frequency Response



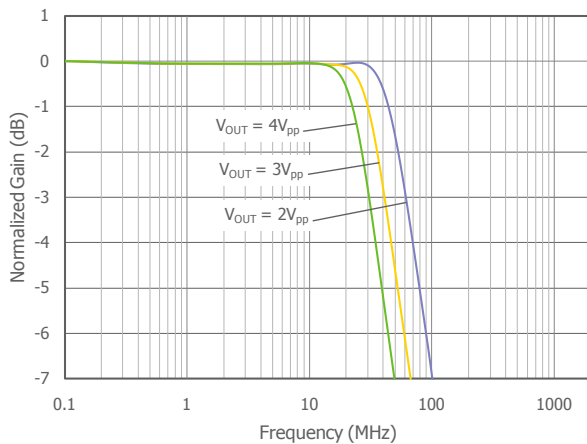
Frequency Response vs. C_L



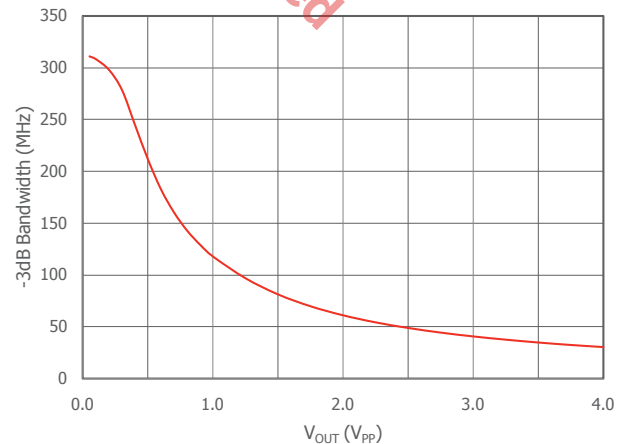
Frequency Response vs. R_L



Frequency Response vs. V_{OUT}



-3dB Bandwidth vs. Output Voltage

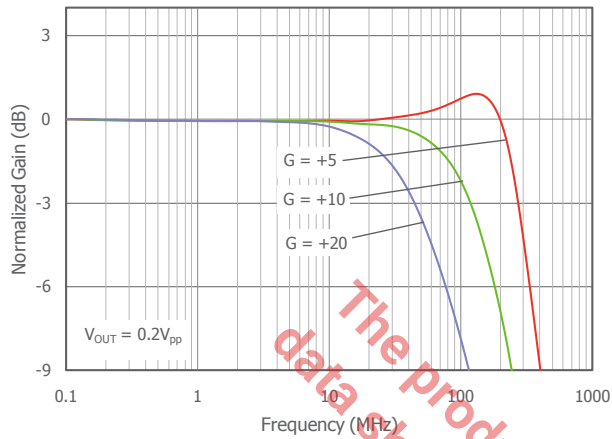




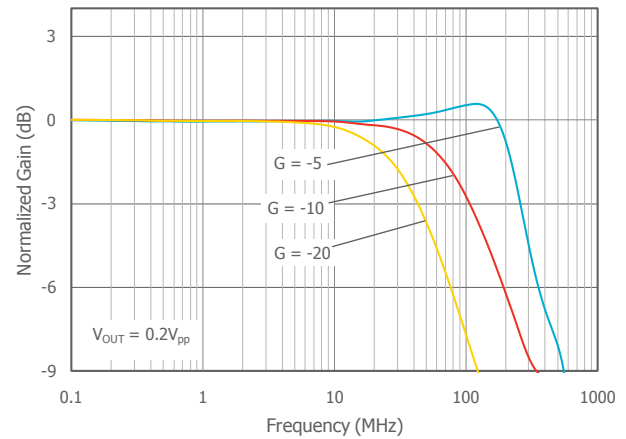
Typical Performance Characteristics

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

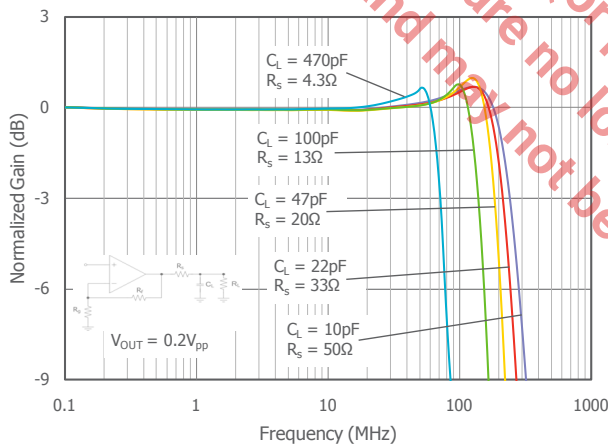
Non-Inverting Frequency Response at $V_S = 5\text{V}$



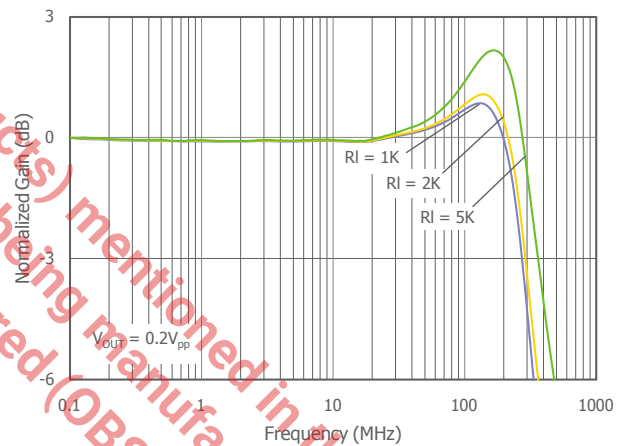
Inverting Frequency Response at $V_S = 5\text{V}$



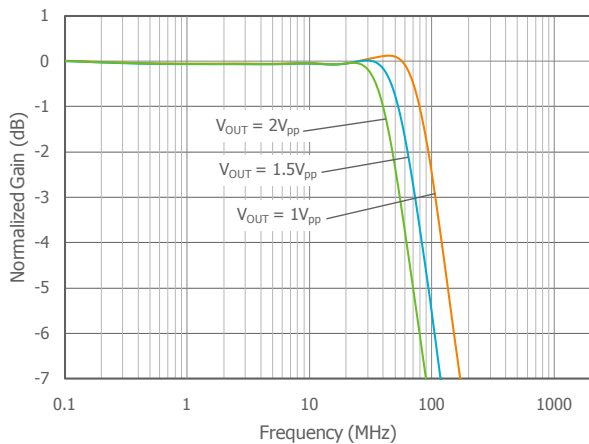
Frequency Response vs. C_L at $V_S = 5\text{V}$



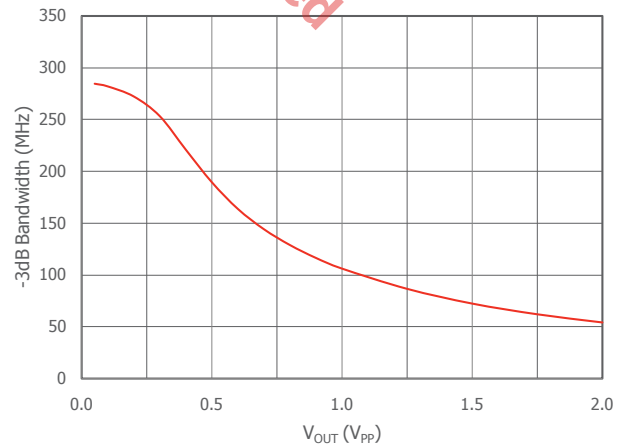
Frequency Response vs. R_L at $V_S = 5\text{V}$



Frequency Response vs. V_{OUT} at $V_S = 5\text{V}$



-3dB Bandwidth vs. Output Voltage at $V_S = 5\text{V}$

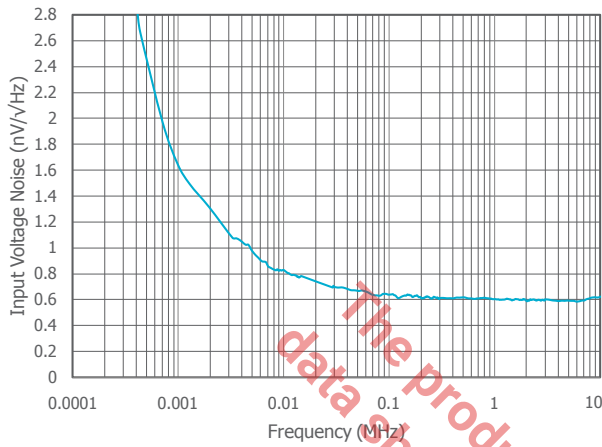




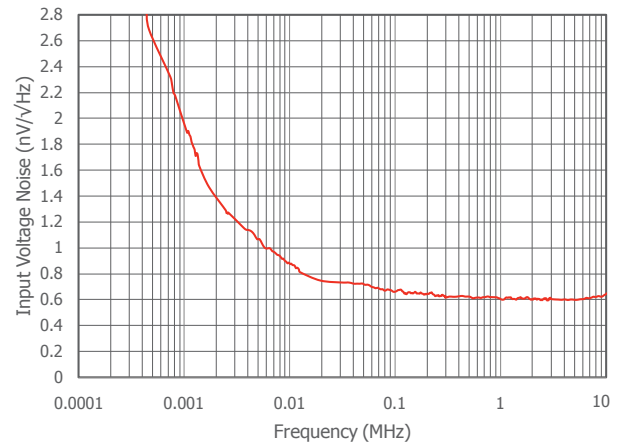
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

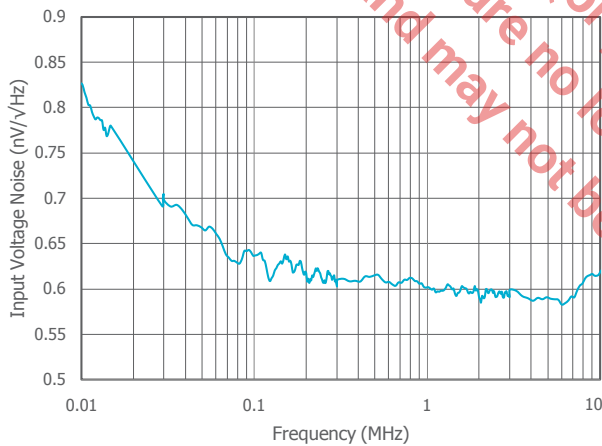
Input Voltage Noise



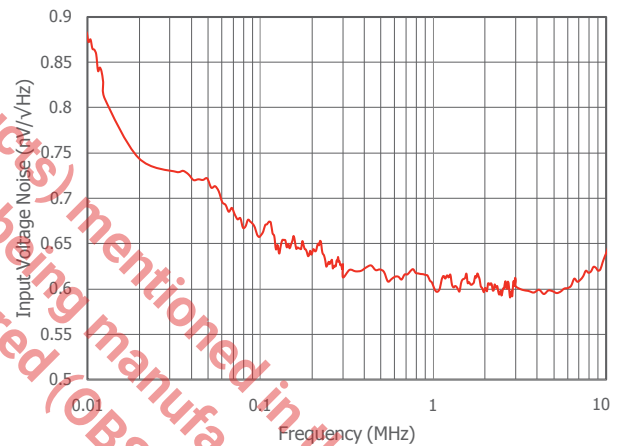
Input Voltage Noise at $V_S = 5\text{V}$



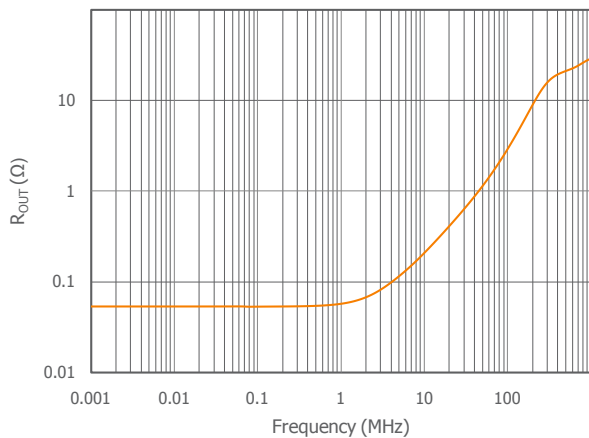
Input Voltage Noise (>10kHz)



Input Voltage Noise at $V_S = 5\text{V}$ (>10kHz)



R_{OUT} vs. Frequency

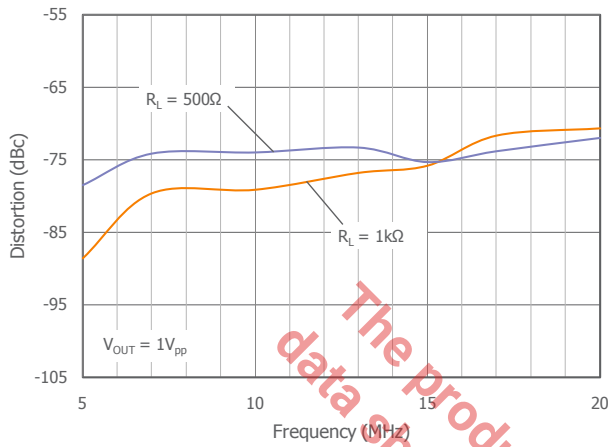




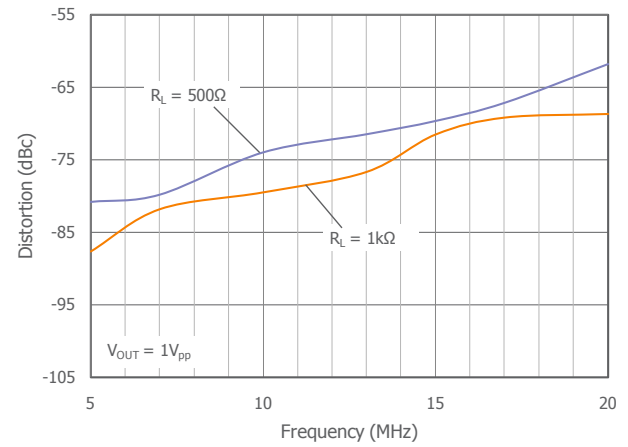
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

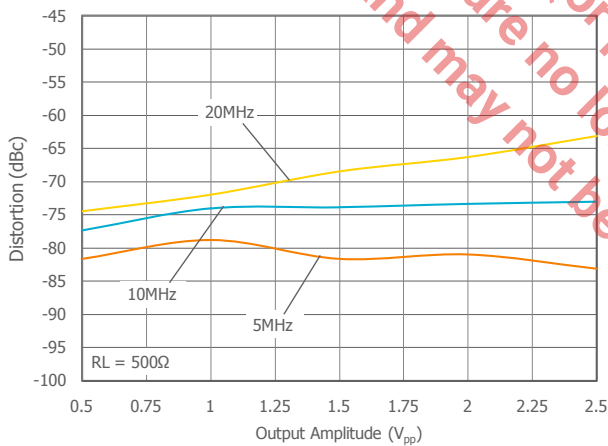
2nd Harmonic Distortion vs. R_L



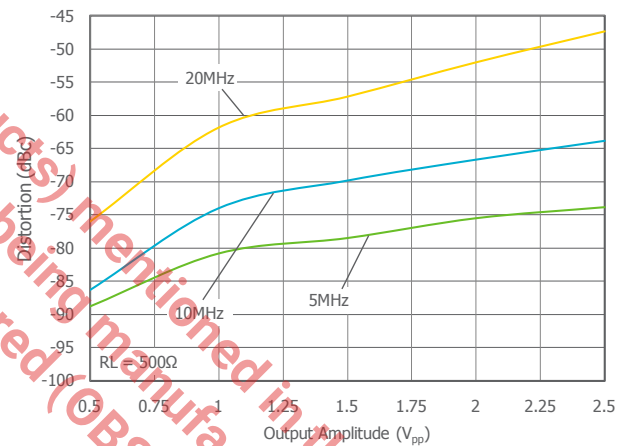
3rd Harmonic Distortion vs. R_L



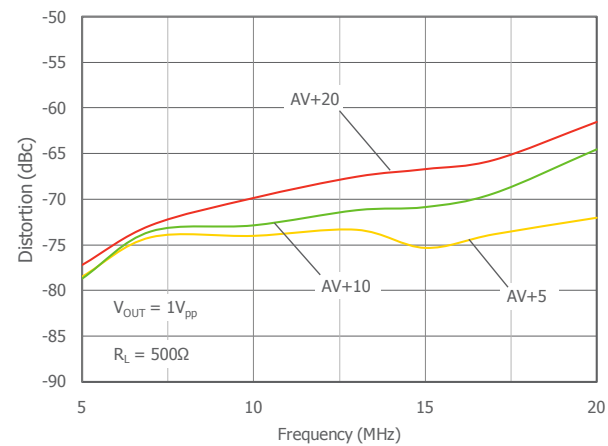
2nd Harmonic Distortion vs. V_{OUT}



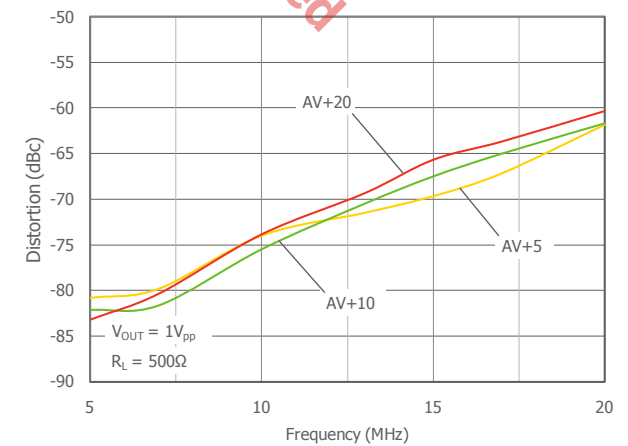
3rd Harmonic Distortion vs. V_{OUT}



2nd Harmonic Distortion vs. Gain



3rd Harmonic Distortion vs. Gain

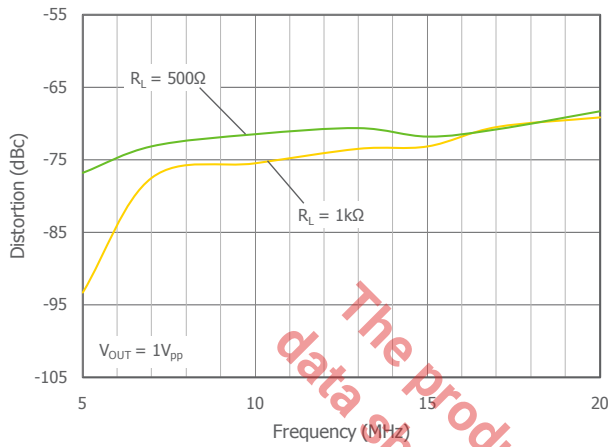




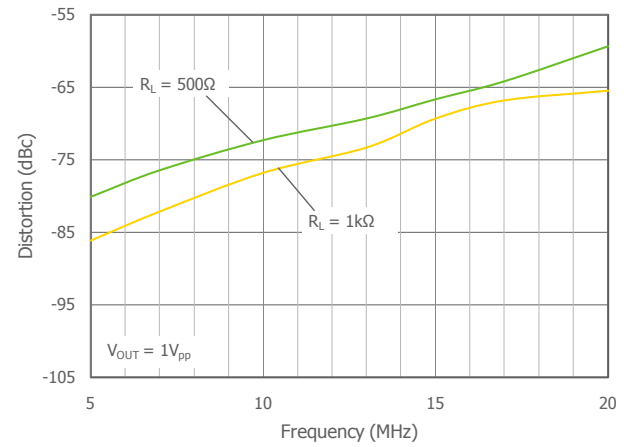
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

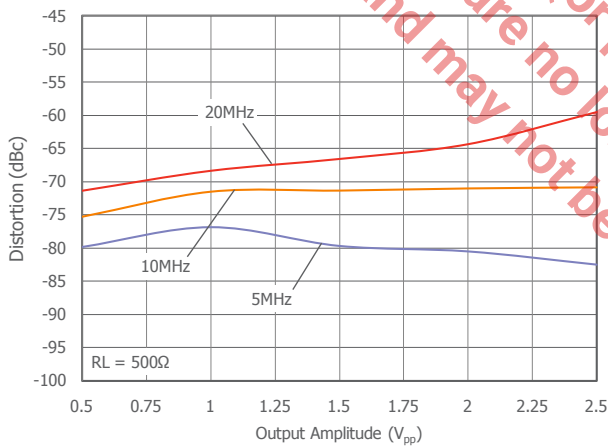
2nd Harmonic Distortion vs. R_L at $V_S = 5\text{V}$



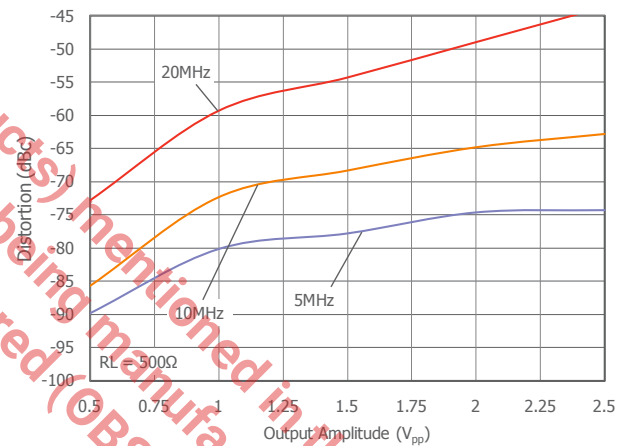
3rd Harmonic Distortion vs. R_L at $V_S = 5\text{V}$



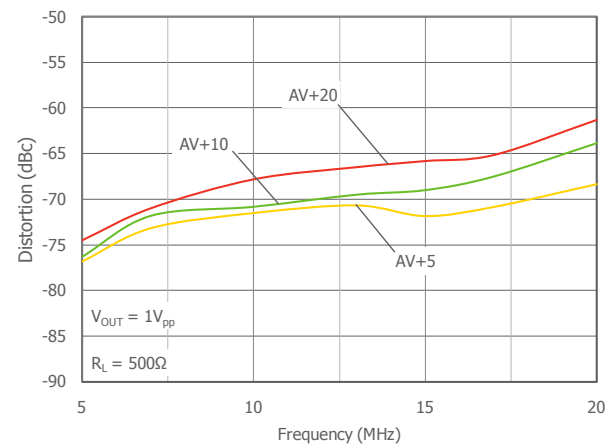
2nd Harmonic Distortion vs. V_{OUT} at $V_S = 5\text{V}$



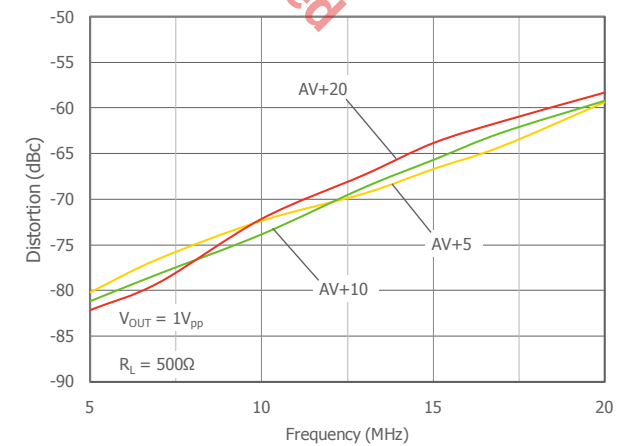
3rd Harmonic Distortion vs. V_{OUT} at $V_S = 5\text{V}$



2nd Harmonic Distortion vs. Gain at $V_S = 5\text{V}$



3rd Harmonic Distortion vs. Gain Freq at $V_S = 5\text{V}$

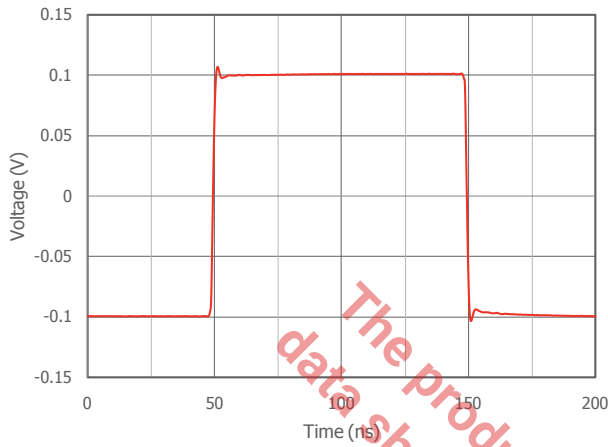




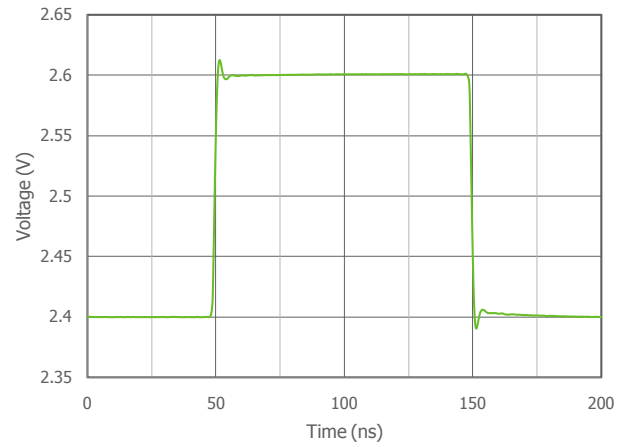
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

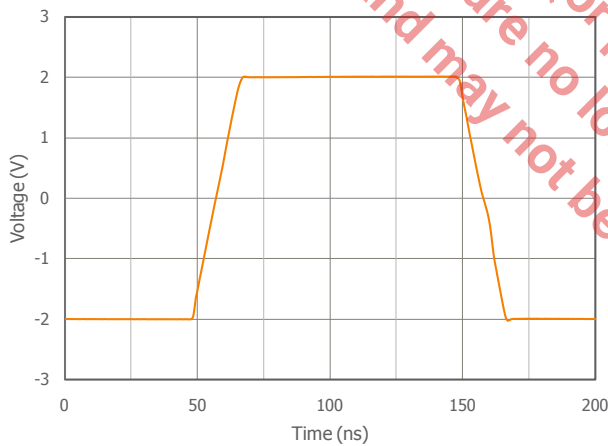
Small Signal Pulse Response



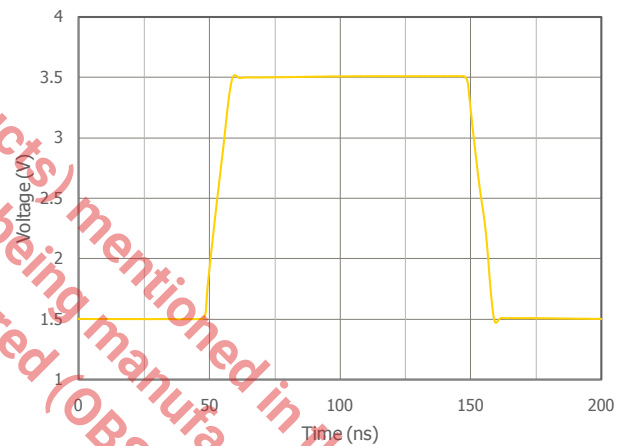
Small Signal Pulse Response at $V_S = 5\text{V}$



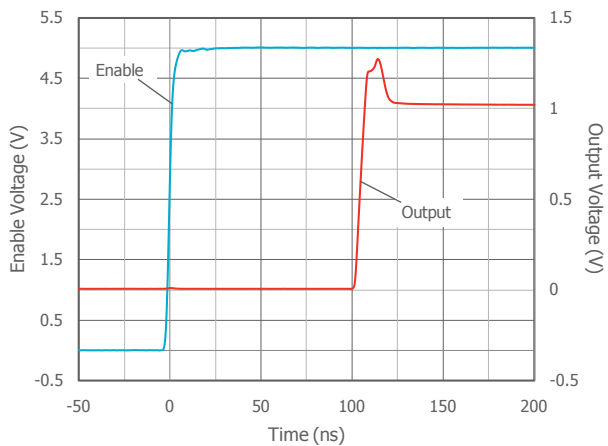
Large Signal Pulse Response



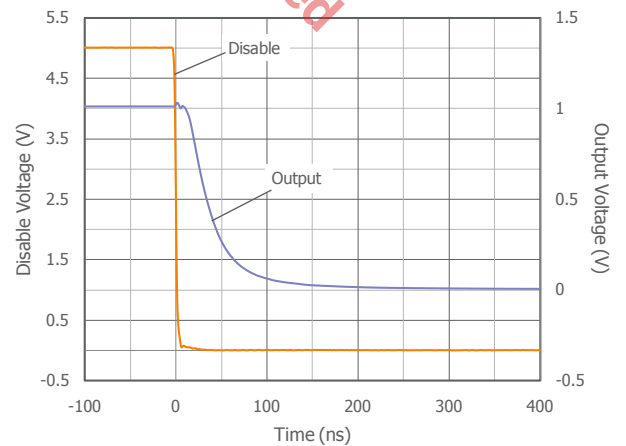
Large Signal Pulse Response at $V_S = 5\text{V}$



Enable Response



Disable Response

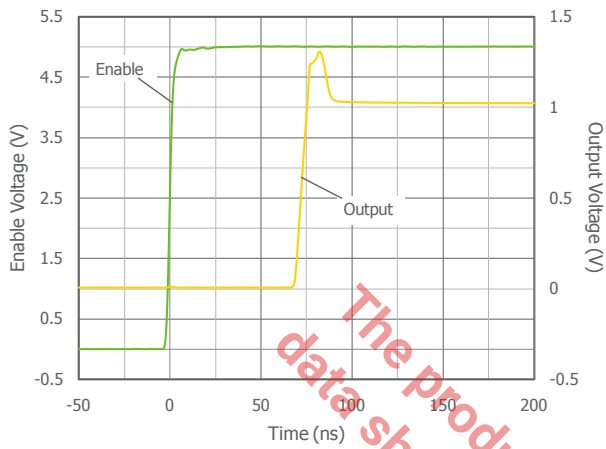




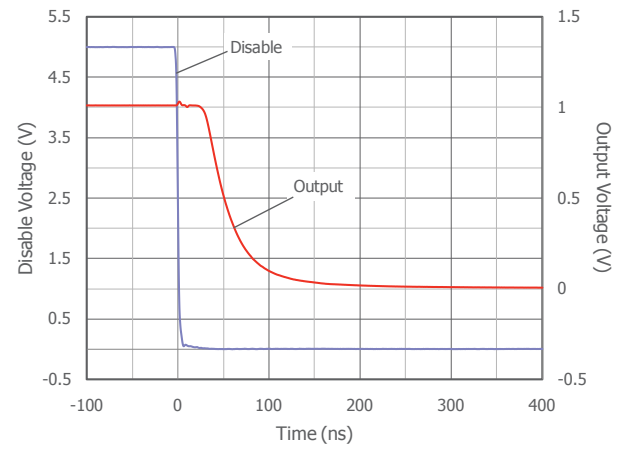
Typical Performance Characteristics - Continued

$T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $R_f = 100\Omega$, $R_L = 500\Omega$, $G = 5$; unless otherwise noted.

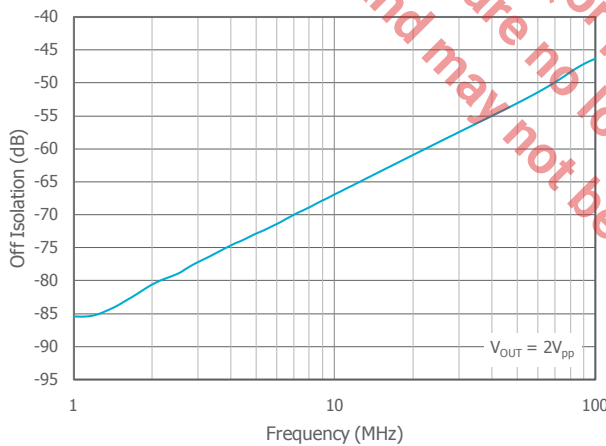
Enable Response at $V_S = 5\text{V}$



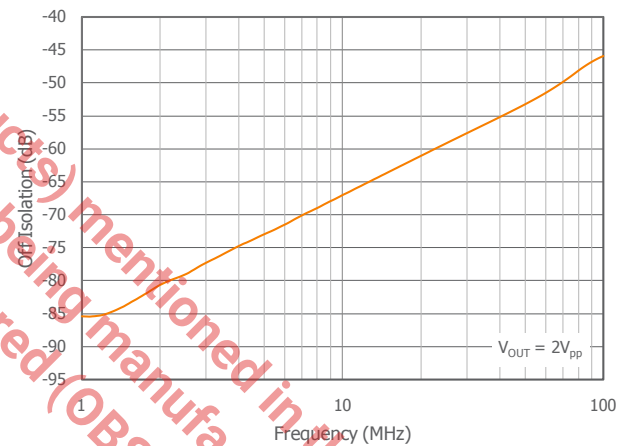
Disable Response at $V_S = 5\text{V}$



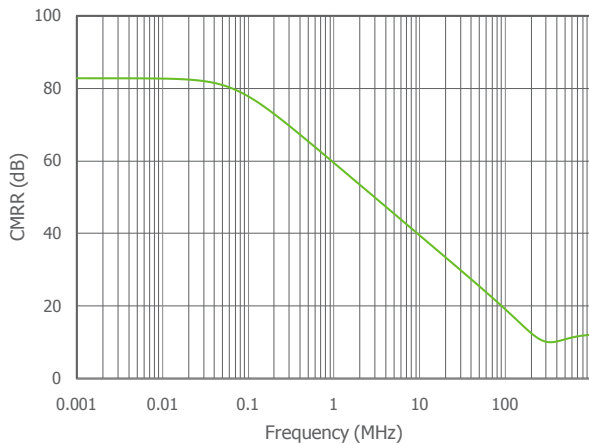
Off Isolation



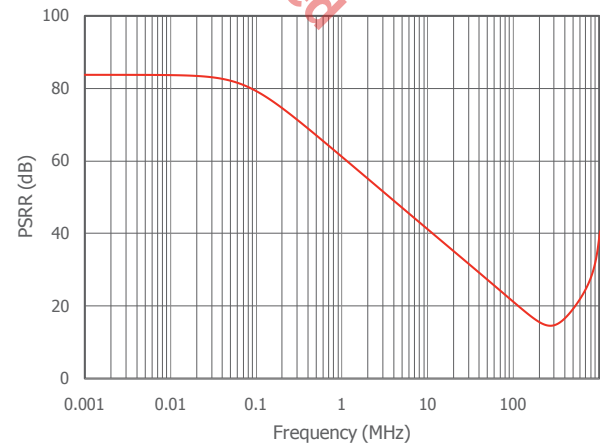
Off Isolation at $V_S = 5\text{V}$



CMRR vs. Frequency



PSRR vs. Frequency





Application Information

Basic Operation

Figures 1 and 2 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

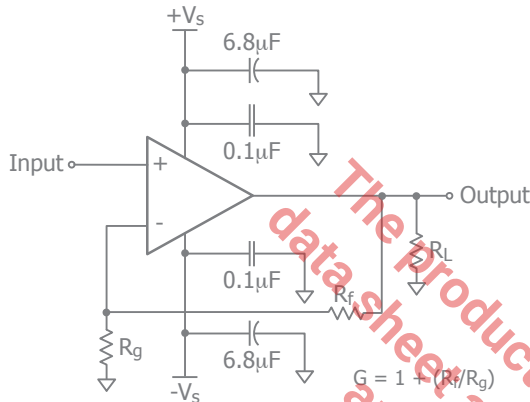


Figure 1. Typical Non-Inverting Gain Circuit

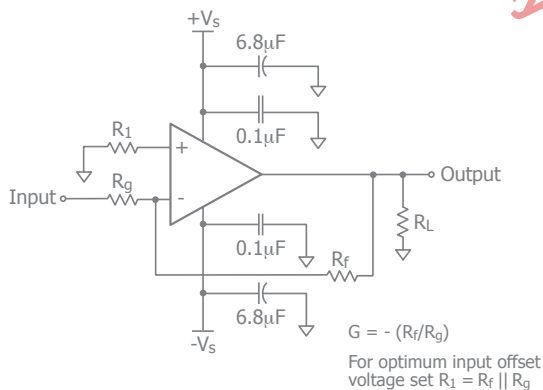


Figure 2. Typical Inverting Gain Circuit

Achieving Low Noise in an Application

Making full use of the low noise of the CLC1002 requires careful consideration of resistor values. The feedback and gain set resistors (R_f and R_g) and the non-inverting source impedance (R_{source}) all contribute noise to the circuit and can easily dominate the overall noise if their values are too high. The datasheet is specified with an R_g of 25Ω, at which point the noise from R_f and R_g is about equal to the noise from the CLC1002. Lower value resistors could be used at the expense of more distortion.

Figure 3 shows total input voltage noise (amp+resistors) versus R_f and R_g . As the value of R_f increases, the total

input referred noise also increases.

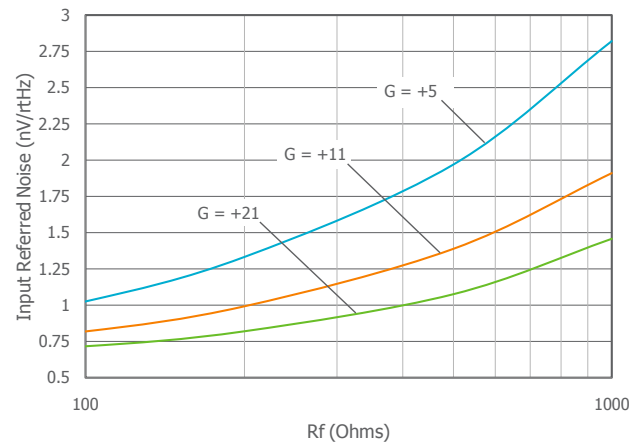


Figure 3: Input Referred Voltage Noise vs. R_f and R_g

The noise caused by a resistor is modeled with either a voltage source in series with the resistance:

$$\sqrt{4kTR}$$

Or a current source in parallel with it:

$$i_R = \sqrt{\frac{4kT}{R}}$$

Op amp noise is modeled with three noise sources, e_n , i_n and i_i . These three sources are analogous to the DC input voltage and current errors V_{os} , I_{bn} and I_{bi} .

The noise models must be analyzed in-circuit to determine the effect on the op amp output noise.

Since noise is statistical in nature rather than a continuous signal, the set of noise sources in circuit add in an RMS (root mean square) fashion rather than in a linear fashion. For uncorrelated noise sources, this means you add the squares of the noise voltages. A typical non-inverting application (see figure 1) results in the following noise at the output of the op amp:

$$e_o^2 = e_n^2 \left(1 + \frac{R_f}{R_g} \right)^2 + i_n^2 R_s^2 \left(1 + \frac{R_f}{R_g} \right)^2 + i_i^2 R_f^2$$

op amp noise terms e_n , i_n and i_i



$$+ e_{R_S}^2 \left(1 + \frac{R_f}{R_g} \right)^2 + e_{R_g}^2 \left(\frac{R_f}{R_g} \right)^2 + e_{R_f}^2$$

external resistor noise terms for R_S , R_g and R_f

High source impedances are sometimes unavoidable, but they increase noise from the source impedance and also make the circuit more sensitive to the op amp current noise. Analyze all noise sources in the circuit, not just the op amp itself, to achieve low noise in your application.

Power Dissipation

Power dissipation should not be a factor when operating under the stated 500Ω load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond its intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Θ_{JA} (Θ_{JA}) is used along with the total die power dissipation.

$$T_{\text{Junction}} = T_{\text{Ambient}} + (\Theta_{JA} \times P_D)$$

Where T_{Ambient} is the temperature of the working environment.

In order to determine P_D , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{\text{supply}} - P_{\text{load}}$$

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$$

$$V_{\text{supply}} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{\text{load}} = ((V_{\text{LOAD}})_{\text{RMS}}^2) / R_{\text{load eff}}$$

The effective load resistor ($R_{\text{load eff}}$) will need to include the effect of the feedback network. For instance, $R_{\text{load eff}}$

in figure 3 would be calculated as:

$$R_L || (R_f + R_g)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here, P_D can be found from

$$P_D = P_{\text{Quiescent}} + P_{\text{Dynamic}} - P_{\text{Load}}$$

Quiescent power can be derived from the specified I_S values along with known supply voltage, V_{Supply} . Load power can be calculated as above with the desired signal amplitudes using:

$$(V_{\text{LOAD}})_{\text{RMS}} = V_{\text{PEAK}} / \sqrt{2}$$

$$(I_{\text{LOAD}})_{\text{RMS}} = (V_{\text{LOAD}})_{\text{RMS}} / R_{\text{load eff}}$$

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{\text{DYNAMIC}} = (V_{S+} - V_{\text{LOAD}})_{\text{RMS}} \times (I_{\text{LOAD}})_{\text{RMS}}$$

Assuming the load is referenced in the middle of the power rails or $V_{\text{supply}}/2$.

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

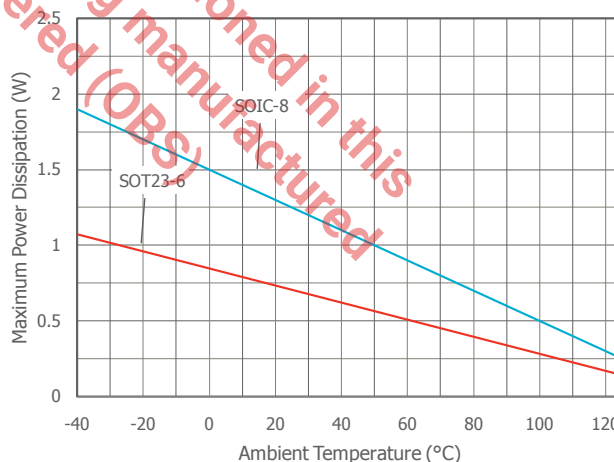


Figure 4. Maximum Power Derating

Driving Capacitive Loads

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance, R_S , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 5.

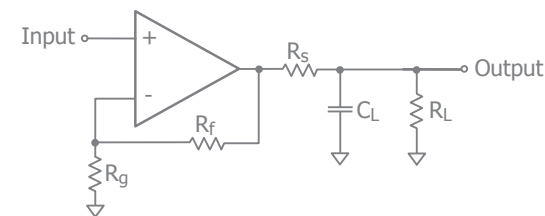


Figure 5. Addition of R_S for Driving Capacitive Loads

Table 1 provides the recommended R_S for various capacitive loads. The recommended R_S values result in ≤ 1 dB peaking in the frequency response. The Frequency Response vs. C_L plots, on page 7, illustrates the response of the CLC1002.

C_L (pF)	R_S (Ω)	-3dB BW (MHz)
10	43	275
22	30	235
47	20	190
100	12	146
470	4.3	72

Table 1: Recommended R_S vs. C_L

For a given load capacitance, adjust R_S to optimize the tradeoff between settling time and bandwidth. In general, reducing R_S will increase bandwidth at the expense of additional overshoot and ringing.

Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLC1002 will typically recover in less than 25ns from an overdrive condition. Figure 6 shows the CLC1002 in an overdriven condition.

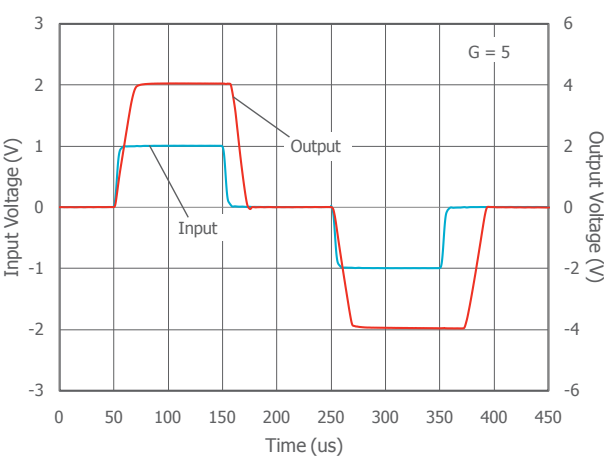


Figure 6. Overdrive Recovery

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Exar has evaluation boards to use as a guide for high frequency layout and as aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8μF and 0.1μF ceramic capacitors for power supply decoupling
- Place the 6.8μF capacitor within 0.75 inches of the power pin
- Place the 0.1μF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts below for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board	Products
CEB002	CLC1002 in SOT23-5
CEB003	CLC1002 in SOIC-8



Evaluation Board Schematics

Evaluation board schematics and layouts are shown in Figures 7-11. These evaluation boards are built for dual-supply operation. Follow these steps to use the board in a single-supply application:

1. Short $-V_S$ to ground.
2. Use C3 and C4, if the $-V_S$ pin of the amplifier is not directly connected to the ground plane.

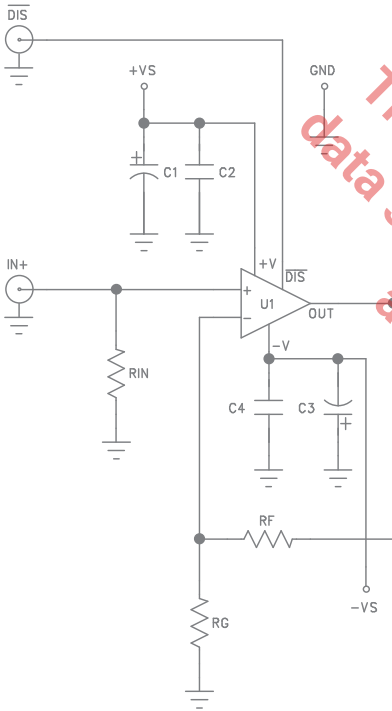


Figure 7. CEB002/CEB003 Schematic

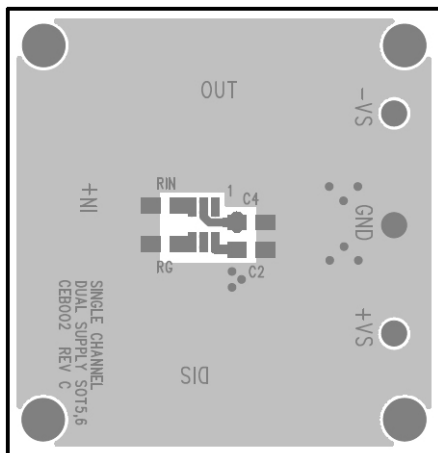


Figure 8. CEB002 Top View

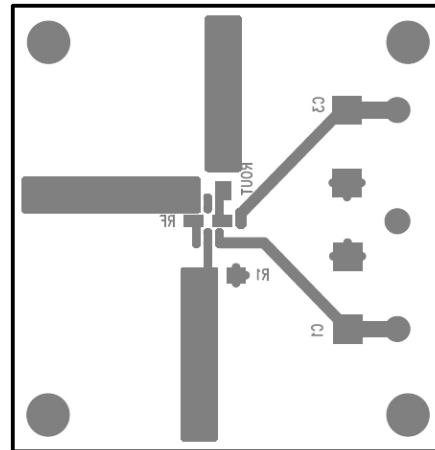


Figure 9. CEB002 Bottom View

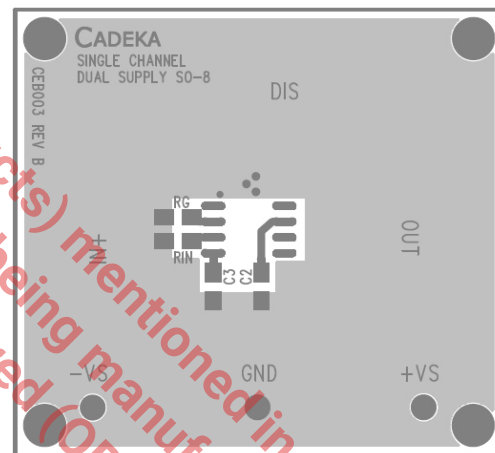


Figure 10. CEB003 Top View

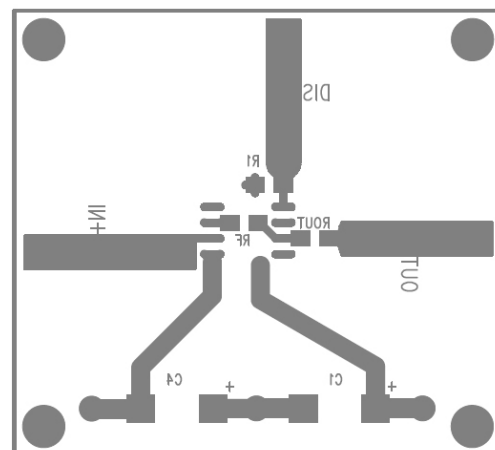
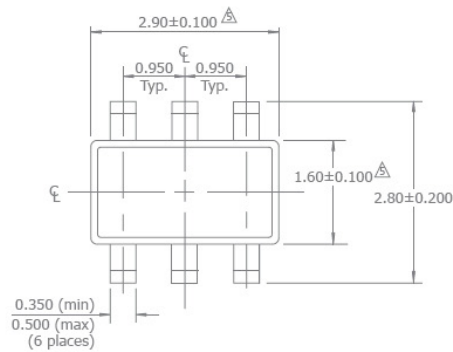


Figure 11. CEB003 Bottom View



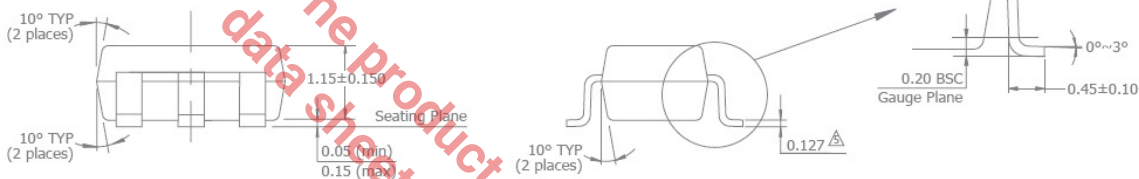
Mechanical Dimensions

SOT23-6 Package

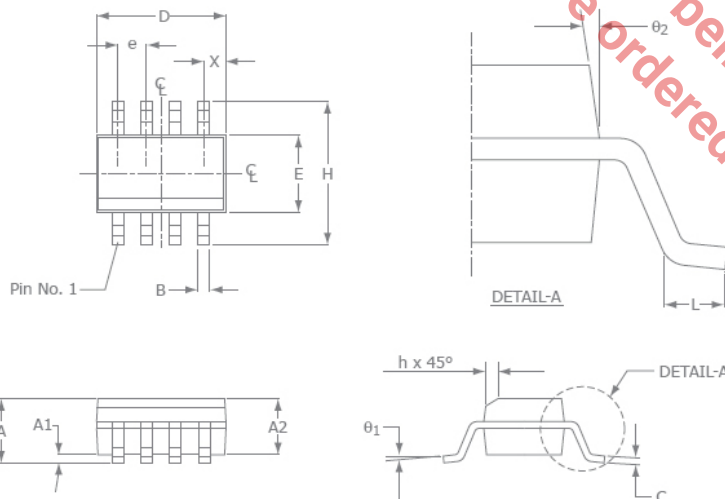


NOTES:

1. Dimensions and tolerances are as per ANSI Y14.5M-1982.
 2. Package surface to be matte finish VDI 11~13.
 3. Die is facing up for mold. Die is facing down for trim/form, ie. reverse trim/form.
 4. The footlength measuring is based on the gauge plane method.
- △ Dimension are exclusive of mold flash and gate burr.
△ Dimension are exclusive of solder plating.



SOIC-8 Package



SOIC-8		
SYMBOL	MIN	MAX
A1	0.10	0.25
B	0.36	0.48
C	0.19	0.25
D	4.80	4.98
E	3.81	3.99
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.5
L	0.41	1.27
A	1.37	1.73
θ1	0°	8°
θ2	0°	8°

NOTE:

1. All dimensions are in millimeters.
2. Lead coplanarity should be 0 to 0.1mm (0.004") max.
3. Package surface finishing: VDI 24~27
4. All dimension excluding mold flashes.
5. The lead width, B to be determined at 0.1905mm from the lead tip.

For Further Assistance:

Exar Corporation Headquarters and Sales Offices
 48720 Kato Road Tel.: +1 (510) 668-7000
 Fremont, CA 94538 - USA Fax: +1 (510) 668-7001
 www.exar.com

NOTICE

EXAR Corporation reserves the right to make changes to the products contained in this publication in order to improve design, performance or reliability. EXAR Corporation assumes no responsibility for the use of any circuits described herein, conveys no license under any patent or other right, and makes no representation that the circuits are free of patent infringement. Charts and schedules contained here in are only for illustration purposes and may vary depending upon a user's specific application. While the information in this publication has been carefully checked; no responsibility, however, is assumed for inaccuracies.

EXAR Corporation does not recommend the use of any of its products in life support applications where the failure or malfunction of the product can reasonably be expected to cause failure of the life support system or to significantly affect its safety or effectiveness. Products are not authorized for use in such applications unless EXAR Corporation receives, in writing, assurances to its satisfaction that: (a) the risk of injury or damage has been minimized; (b) the user assumes all such risks; (c) potential liability of EXAR Corporation is adequately protected under the circumstances.

Reproduction, in part or whole, without the prior written consent of EXAR Corporation is prohibited.



A New Direction in Mixed-Signal